NSN 5961-01-231-1416

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-231-1416 **Inclosure Material:** Metal **Overall Length:** 0.785 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.200 inches **Overall Width:** 0.265 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 drain to source voltage all transistor and 60.0 drain to gate voltage all transistor **Current Rating Per Characteristic:** 900.00 milliamperes drain current all transistor **Power Rating Per Characteristic:** 1200.0 milliwatts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Electrostatic discharge **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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